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Vishay Semiconductor/Diodes Division VS-UFB120FA20P

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UFB120FA20P

Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 120 A



SOT-227

PRODUCT SUMMARY			
V _R	200 V		
$I_{F(AV)}$ at $T_{C} = 90 \ ^{\circ}C$	120 A		
t _{rr}	28 ns		

FEATURES

- Two fully independent diodes
- Ceramic fully insulated package (V_{ISOL} = 2500 V_{AC})
- Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape
- Low forward voltage
- Optimized for power conversion: welding and industrial SMPS applications
- Industry standard outline
- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- Direct mounting to heatsink
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The UFB120FA20P insulated modules integrate two state of the art Vishay Semiconductors ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		200	V	
Continuous forward current per diode	١ _F	T _C = 90 °C	60	А	
Single pulse forward current per diode	I _{FSM}	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	850		
Maximum power dissipation per module	PD	T _C = 90 °C	110	W	
RMS isolation voltage	VISOL	Any terminal to case, t = 1 min	2500	V	
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 150	°C	



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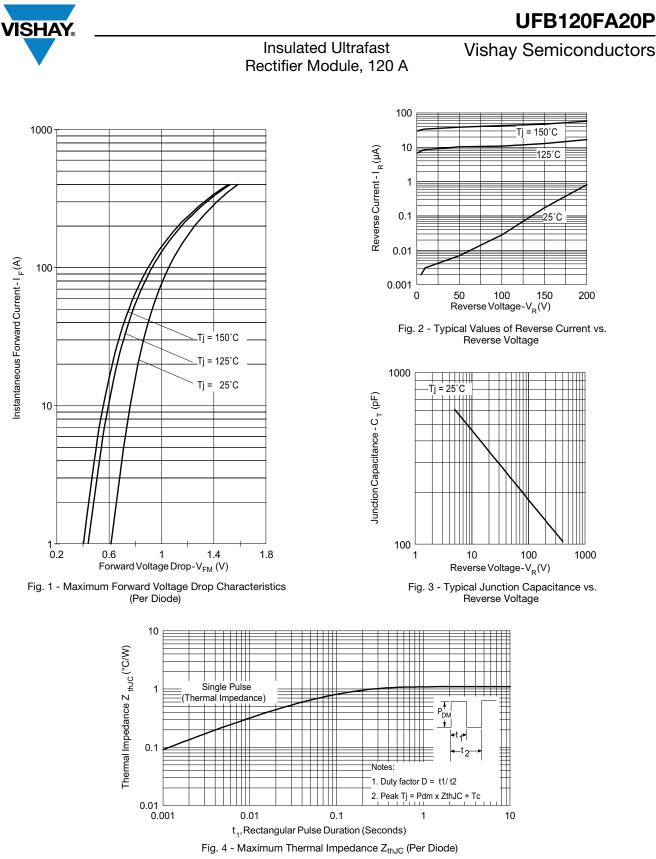


ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	200	-	-	
Forward voltage V _{FM}	V-	I _F = 60 A	-	0.96	1.13	V
	I _F = 60 A, T _J = 150 °C	-	0.79	0.90		
Reverse leakage current I _{RI}	1	$V_R = V_R$ rated	-	-	100	μA
	I _{RM}	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1.0	mA
Junction capacitance	CT	V _R = 200 V	-	105	-	pF

DYNAMIC RECOVERY CHARACTERISTICS PER DIODE (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \ dI_F/dt = 200 \text{ A}/\mu \text{s}, \ V_R = 30 \text{ V}$		-	-	28	
Reverse recovery time	Reverse recovery time t _{rr}	T _J = 25 °C	I _F = 50 A dI _F /dt = 200 A/μs V _R = 100 V	-	32	-	ns
		T _J = 125 °C		-	64	-	
Peak recovery current I _{RI}		T _J = 25 °C		-	4.0	-	A
	I _{RRM}	T _J = 125 °C		-	8.2	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	64	-	nC
		T _J = 125 °C		-	263	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single diode conducting	P		-	0.8	1.1	к/w
Junction to case, both diodes conducting	— R _{thJC}		-	0.4	0.55	
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm





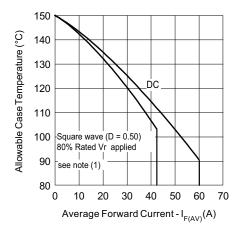


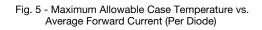
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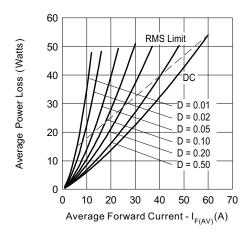


Fig. 6 - Forward Power Loss (Per Diode)

Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC};$ Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

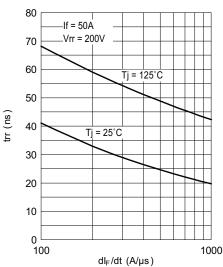
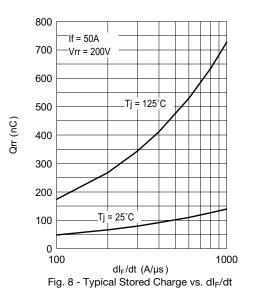


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt







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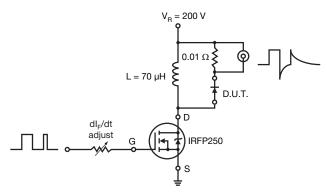
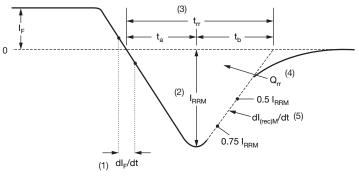


Fig. 9 - Reverse Recovery Parameter Test Circuit



(1) dl_F/dt - rate of change of current through zero crossing

(4) ${\rm Q}_{\rm rr}$ - area under curve defined by ${\rm t}_{\rm rr}$ and ${\rm I}_{\rm RRM}$

(2) ${\rm I}_{\rm RRM}$ - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



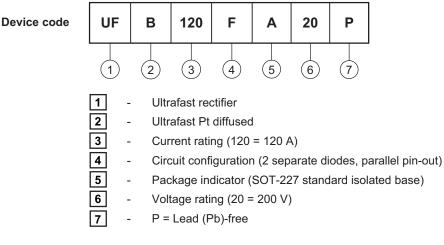
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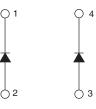
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95036					
Packaging information	www.vishay.com/doc?95037				



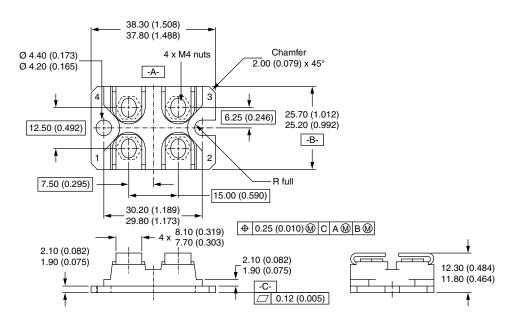


Outline Dimensions

Vishay Semiconductors

SOT-227

DIMENSIONS in millimeters (inches)



Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter





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